



#### 20V PNP SURFACE MOUNT TRANSISTOR

### Features

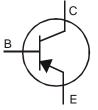
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DCP68)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

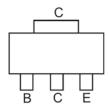
- Case: SOT223
- Case Material: Molded Plastic, "Green Molding" Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin
- Solderable per MIL-STD -202, Method 208
- Weight: 0.112 grams (Approximate)



Top View



**Device Schematic** 



Top View Pin Out Configuration

### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DCP69-13	P12	13	12	2500
DCP69-16-13	P12-16	13	12	2500
DCP69-25-13	P12-25	13	12	2500

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant..

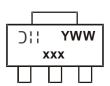
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**

Notes:



xxx = Product Type Marking Code P12 = DCP69 P12-16 = DCP69-16 P12-25 = DCP69-25 OIII = Manufacturer's code marking YWW = Date Code Marking Y = Last digit of year (ex: 8 = 2018) WW = Week code (01 - 53)



### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Collector-Base Voltage	V <sub>CBO</sub>	-25	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	Ιc	-1	A
Peak Pulse Current	I <sub>CM</sub>	-2	A

# Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	R <sub>ÐJA</sub>	125	°C/W
Power Dissipation (Note 6)	PD	2	W
Thermal Resistance, Junction to Ambient Air (Note 6)	R <sub>ƏJA</sub>	62.5	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

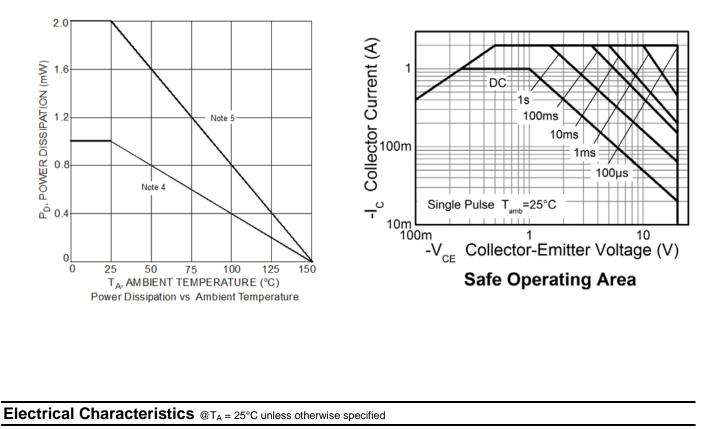
### ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes: 5. Device mounted on FR-4 PCB; pad layout as shown on in Diodes Inc. suggested pad layout document, which can be found on our website at http://www.diodes.com. 6. Device mounted on FR-4 PCB with 1in<sup>2</sup> copper pad layout 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**



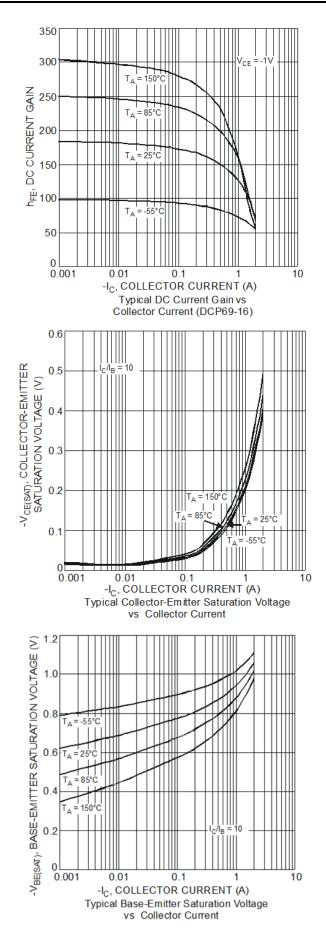
# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

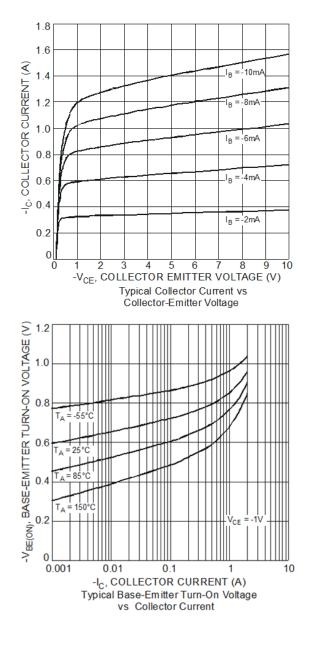
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERI	STICS						
Collector-Base Breakdown Voltage		<b>BV</b> CBO	-25	_	_	V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 8)		<b>BV</b> CEO	-20		_	V	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Break	down Voltage	BV <sub>EBO</sub>	-5			V	$I_{\rm E} = -100 \mu A, I_{\rm C} = 0$
Collector-Base Cutoff Current		I <sub>CBO</sub>	—	—	-100 -10	nA μA	V <sub>CB</sub> = -25V, I <sub>E</sub> = 0 V <sub>CB</sub> = -25V, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C
Emitter-Base Cutoff Current		I <sub>EBO</sub>	—	_	-100	nA	$V_{EB} = -5.0V, I_{C} = 0$
<b>ON CHARACTERIS</b>	TICS (Note 8)						•
DC Current Gain	DCP69, DCP69-16, DCP69-25		50 60				$V_{CE} = -10V, I_C = -5.0mA$ $V_{CE} = -1V, I_C = -1A$
	DCP69		85	_	375	—	$V_{CE} = -1V, I_{C} = -500mA$
	DCP69-16		100	-	250		V <sub>CE</sub> = -1V, I <sub>C</sub> = -500mA
	DCP69-25		160	_	375		$V_{CE} = -1V, I_{C} = -500mA$
Collector-Emitter Sa	turation Voltage	V <sub>CE(sat)</sub>	—	-	-0.5	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Base-Emitter Turn-On Voltage		V <sub>BE (on)</sub>	_	_	-0.7 -1	V	$V_{CE} = -10V, I_C = -5.0mA$ $V_{CE} = -1V, I_C = -1A$
SMALL SIGNAL CH	IARACTERISTICS						
Current Gain-Bandwidth Product		f <sub>T</sub>	40	200	—	MHz	$V_{CE} = -5V, I_{C} = -50mA, f = 100MHz$
Output Capacitance		Cobo	_	17	_	pF	V <sub>CB</sub> = -10V, f = 1 MHz

8. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ . Notes:

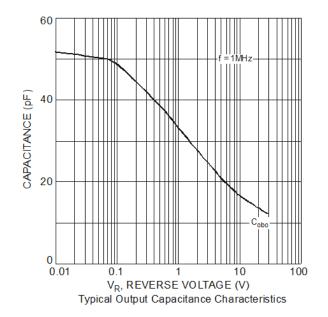


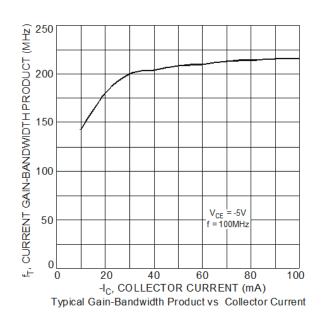
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







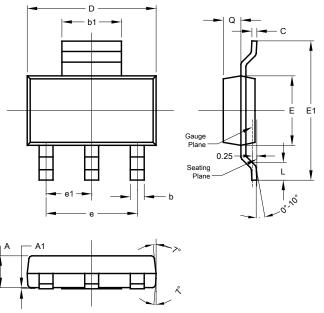






# **Package Outline Dimensions**

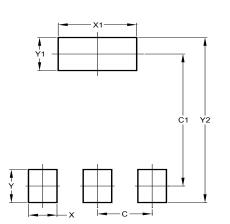
Please see http://www.diodes.com/package-outlines.html for the latest version. SOT223



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
e	—		4.60		
e1	_		2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All I	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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